

Technical Data Sheet

1.6mm Side Looking Infrared Emitting Diode

IR958-8C

Features

- Low forward voltage
- Peak wavelength λ p=940nm
- High reliability
- This product itself will remain within RoHS compliant version.



Descriptions

The <u>IR958-8C</u> is a GaAs infrared emitting diode. The miniature side-facing device is a chip that emits radiation from the side of the clear package.

Applications

- VCR
- Floppy disk drive
- Automatic stroboscope
- Cassette type recorder
- Optoelectronic switch
- Photo interrupter

Device Selection Guide

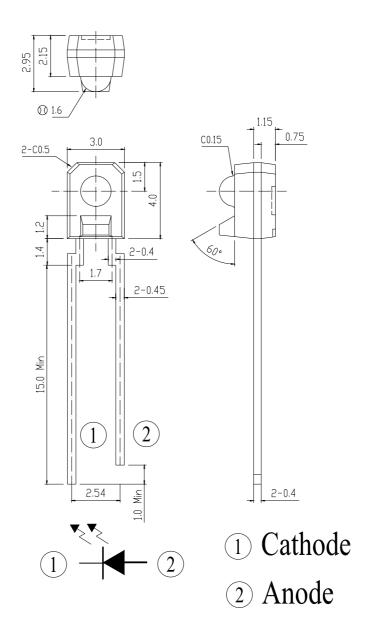
Don't No	Chip	Lens Color	
Part No.	Material		
IR958-8C	GaAs/GaAlAs	Water clear	

Everlight Electronics Co., Ltd. http:\\www.everlight.com Rev 1 Page: 1 of 8

Device No: CDIR-095-001 Prepared date: 2005/12/13 Prepared by: Fealty zhu



Package Dimensions



Notes: 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.25mm

Everlight Electronics Co., Ltd. Device No: CDIR-095-001 http:\\www.everlight.com

Rev 1

Page: 2 of 8

Prepared date : 2005/12/13

Prepared by : Fealty zhu



Absolute Maximum Ratings (Ta=25°C)

Item	Symbol	Rating	Unit
Power Dissipation	P_{D}	75	mW
Reverse Voltage	V_{R}	5	V
Forward Current	I_{F}	50	mA
Peak Forward Current (*1)	$ m I_{FP}$	1	A
Operating Temperature	Topr	-25~+85	$^{\circ}\!\mathbb{C}$
Storage Temperature	Tstg	-40~+85	$^{\circ}\!\mathbb{C}$
Soldering Temperature (1/16 inch from body for 5 seconds)	Tsol	260	$^{\circ}\!\mathbb{C}$

Notes: *1: I_{FP} Conditions--Pulse Width \leq 100 μ s and Duty \leq 1%.

Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Collector Current	Ic(on)	306	-	1870	μ A	$I_F=4\text{mA}, V_{CE}=3.5\text{V}$
Peak Wavelength	λр	-	950	-	nm	I _F =20mA
Spectral Bandwidth	Δλ	-	40	1	nm	$I_F = 20 \text{mA}$
View Angle	2 \theta 1/2	-	25	-	Deg	$I_F = 20 \text{mA}$
Forward Voltage	V_{F}	-	1.2	1.5	V	$I_F = 20 \text{mA}$
Reverse Current	I_R	-	1	10	μ A	$V_R=5V$

Everlight Electronics Co., Ltd. http:\\www.everlight.com Rev 1 Page: 3 of 8

Device No: CDIR-095-001 Prepared date: 2005/12/13 Prepared by: Fealty zhu

^{*2:}Soldering time ≤ 5 seconds.



Typical Electrical/Optical/Characteristics Curves

Fig.1 Forward Current vs.

Ambient Temperature

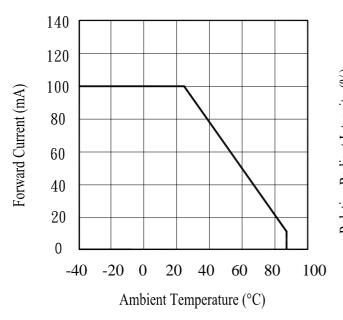


Fig.2 Spectral Distribution

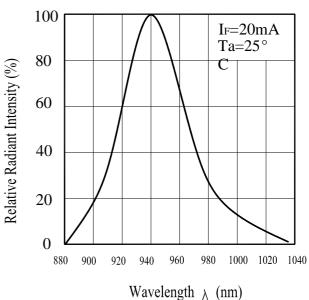


Fig.3 Peak Emission Wavelength
Ambient Temperature

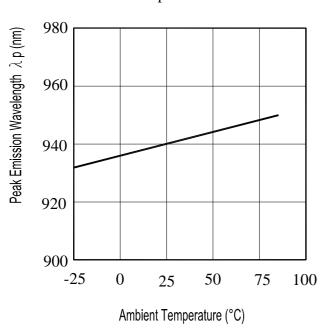
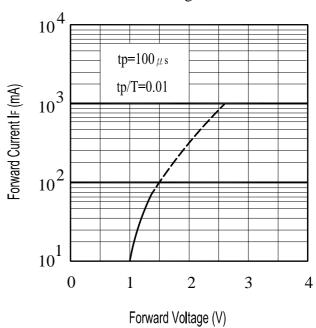


Fig.4 Forward Current vs. Forward Voltage



Everlight Electronics Co., Ltd. Device No: CDIR-095-001

 $http: \hspace{-0.05cm} \backslash www.everlight.com$

Rev 1

Page: 4 of 8

Prepared date: 2005/12/13 Prepared by: Fealty zhu



. Fig5 Forward Voltage vs. Ambient Temperature(°C)

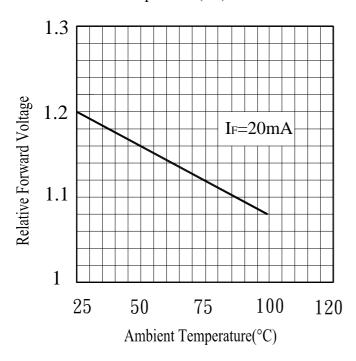
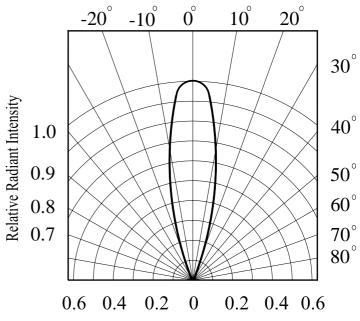


Fig.6 Relative Radiant Intensity vs. Angular Displacement $20^{\circ} -10^{\circ} \quad 0^{\circ} \quad 10^{\circ} \quad 20^{\circ}$



Everlight Electronics Co., Ltd.

Device No: CDIR-095-001

http://www.everlight.com

Prepared date : 2005/12/13

Rev 1

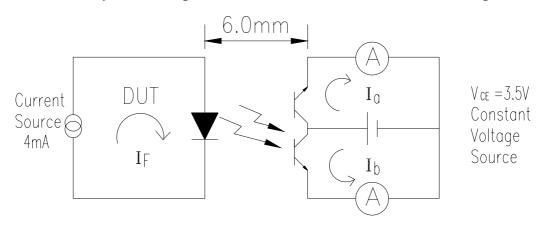
Page: 5 of 8

Prepared by : Fealty zhu



Test Method

The intensity testing method of Infrared emitting diode:



To Distinguish Intensity:

Ranks

Parameter	Symbol	Min	Max	Unit	Test Condition
5-2	Ic(ON)	1053	1870	μ A	$I_F=4\text{mA}, V_{CE}=3.5\text{V}$
6-1	Ic(ON)	650	1274	μ A	$I_F=4\text{mA}, V_{CE}=3.5\text{V}$
6-2	Ic(ON)	465	750	μ A	$I_F=4\text{mA}, V_{CE}=3.5\text{V}$
7-1	Ic(ON)	347	550	μ A	$I_F=4\text{mA}, V_{CE}=3.5\text{V}$
7-2	Ic(ON)	306	441	μ A	I _F =4mA, V _{CE} =3.5V

Everlight Electronics Co., Ltd. http:\\www.everlight.com Rev 1 Page: 6 of 8

Device No: CDIR-095-001 Prepared date: 2005/12/13 Prepared by: Fealty zhu



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Conditions	Test Hours/	Sample	Failure	Ac/Re
			Cycles	Sizes	Judgement	
					Criteria	
1	Solder Heat	TEMP. : 260°C±5°C	10secs	22pcs		0/1
2	Temperature Cycle	$H:+100^{\circ}C$ 15mins	300Cycles	22pcs	$I_R \ge U \times 2$	0/1
		5mins			Ee≦Lx0.8	
		L: -40°C 15mins			$V_F \ge U \times 1.2$	
3	Thermal Shock	H :+100°C	300Cycles	22pcs		0/1
		↓ 10secs			U: Upper	
		L :-10°C 5mins			Specification	
4	High Temperature	TEMP. ∶ +100°C	1000hrs	22pcs	Limit	0/1
	Storage				L: Lower	
5	Low Temperature	TEMP. : -40°C	1000hrs	22pcs	Specification	0/1
	Storage				Limit	
6	DC Operating Life	$I_F=20mA$	1000hrs	22pcs		0/1
7	High Temperature/	85°C / 85% R.H	1000hrs	22pcs		0/1
	High Humidity					

Everlight Electronics Co., Ltd. http:\\www.everlight.com Rev 1 Page: 7 of 8

Device No: CDIR-095-001 Prepared date: 2005/12/13 Prepared by: Fealty zhu



Packing Quantity Specification

- 1.1000PCS/1Bag , 8Bags/1Box
- 2.10Boxes/1Carton

Label Form Specification

EVERLIGHT

CPN: P/N:

IR958-8C

QTY: LOT NO:

CAT: HUE:



CPN: Customer's Production Number

P/N: Production Number QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
- 3. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.

EVERLIGHT ELECTRONICS CO., LTD.

Office: No 25, Lane 76, Sec 3, Chung Yang Rd, Tucheng, Taipei 236, Taiwan, R.O.C

Fax: 886-2267-6244, 2267-6189, 2267-6306

Tel: 886-2-2267-2000, 2267-9936

http:\\www.everlight.com

Rev 1 Everlight Electronics Co., Ltd. http:\\www.everlight.com Page: 8 of 8 Device No: CDIR-095-001 Prepared date : 2005/12/13 Prepared by: Fealty zhu